L Number	Hits	Search Text	DB	Time stamp
38	5141	semiconductor near laser near diode	USPAT;	2003/07/27 12:53
			US-PGPUB;	
			EPO; JPO;	
			DERWENT	0000/27/27
39	28	(semiconductor near laser near diode) and passive\$3 near3	USPAT;	2003/07/27 13:14
		mode near3 lock\$3	US-PGPUB;	
			EPO; JPO;	
			DERWENT	l
40	23	((semiconductor near laser near diode) and passive\$3 near3	USPAT;	2003/07/27 12:55
		mode near3 lock\$3) and method	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
41	17	(semiconductor near laser near diode) and passive\$3 near3	USPAT;	2003/07/27 13:14
		resonator	US-PGPUB;	
1			EPO; JPO;	
1			DERWENT	
42	6	((semiconductor near laser near diode) and passive\$3 near3	USPAT;	2003/07/27 13:25
		resonator) and mode near3 lock\$3	US-PGPUB;	
I			EPO; JPO;	
			DERWENT	
44	8	((passive near3 resonat\$3) and mode near3 lock\$3) and (align\$4	USPAT;	2003/07/27 13:32
		or misalign\$4)	US-PGPUB;	İ
			EPO; JPO;	
			DERWENT	
45	6	((passive near3 resonat\$3) and mode near3 lock\$3) and mirror\$1	USPAT;	2003/07/27 13:33
		near3 (adjust\$4 or rotat\$4)	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
46	1		USPAT	2003/07/27 13:43
47	1		USPAT	2003/07/27 13:44
48	1		USPAT	2003/07/27 13:44
49	1		USPAT	2003/07/27 13:44
50	1		USPAT	2003/07/27 13:45
51	1	·	USPAT	2003/07/27 13:45
43	33	(passive near3 resonat\$3) and mode near3 lock\$3	USPAT;	2003/07/27 14:02
			US-PGPUB;	Ť
			EPO; JPO;	
			DERWENT	
52	252	semiconductor near3 ring near3 laser	USPAT;	2003/07/27 13:53
			US-PGPUB;	
			EPO; JPO;	ļ
i			DERWENT	
53	4	(semiconductor near3 ring near3 laser) and (passive\$3 near3	USPAT;	2003/07/27 13:55
		mode near3 lock\$3)	US-PGPUB,	
			EPO; JPO;	
			DERWENT	
55	1	((semiconductor near3 ring near3 laser) and passive near3	USPAT;	2003/07/27 13:55
İ		resonat\$3) and mode near3 lock\$3	US-PGPUB;	[
ì			EPO; JPO;	
			DERWENT	
54	23	(semiconductor near3 ring near3 laser) and passive near3	USPAT;	2003/07/27 13:56
		resonat\$3	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
56	102	(passive near3 resonat\$3) and ((frequency or mode) near3	USPAT;	2003/07/27 14:03
		lock\$3)	US-PGPUB;	
			EPO; JPO;	
			DERWENT	
	100011	semiconductor near5 laser	USPAT;	2003/07/27 14:04
57		Commoditation near a labor		2000/01/27 11:01
57	100011		I UO-FGFUD	
57	100011		US-PGPUB;	
57	100011		EPO; JPO;	
:		((nassive near3 resonat\$3) and ((frequency or mode) near3	EPO; JPO; DERWENT	2003/07/27 14:00
57	36	((passive near3 resonat\$3) and ((frequency or mode) near3	EPO; JPO; DERWENT USPAT;	2003/07/27 14:09
:		((passive near3 resonat\$3) and ((frequency or mode) near3 lock\$3)) and semiconductor near5 laser	EPO; JPO; DERWENT	2003/07/27 14:09

59	5	"5383198"	USPAT;	2003/07/27 14:09
			US-PGPUB;	
			EPO; JPO;	
⋄		·	DERWENT	
60	1	("5383198").PN.	USPAT;	2003/07/27 14:10
			US-PGPUB	
61	31	(laser near3 diode) and ((frequency or mode) near3 lock\$3) and	USPAT;	2003/07/27 14:15
		passive near3 resonat\$3	US-PGPUB;	
		•	EPO; JPO;	
			DERWENT	
62	19	((laser near3 diode) and ((frequency or mode) near3 lock\$3) and	USPAT;	2003/07/27 14:29
		passive near3 resonat\$3) and (align\$4 or misalign\$4 or	US-PGPUB;	
		realign\$4)	EPO; JPO;	
			DERWENT	
63	6	(semiconductor near3 laser near3 diode) and (passive near3	USPAT;	2003/07/27 14:34
		resonator) and (mode near3 lock\$3)	US-PGPUB;	
		(EPO; JPO;	
			DERWENT	
64	1	(semiconductor near3 laser near3 diode) and (passive near3	USPAT;	2003/07/27 14:35
0.		resonator) and (self near3 mode near3 lock\$3)	US-PGPUB;	
		1000 natory and (0011 nouro mode nouro 1001140)	EPO; JPO;	
			DERWENT	
65	3	(passive near3 resonator) and (self near3 mode near3 lock\$3)	USPAT:	2003/07/27 14:36
05	3	(passive flears resolution) and (sell flears flode flears lockws)	US-PGPUB;	2000/01/21 14:00
			EPO; JPO;	
	İ		DERWENT	
66	248	(solf near? made near? lock\$3)	USPAT:	2003/07/27 14:36
00	240	(self near3 mode near3 lock\$3)	US-PGPUB;	2003/01/21 14.30
				·
			EPO; JPO;	
07	00	/ /- If 0 d 0 ! I-00)} d !	DERWENT	2002/07/07 44-27
67	69	((self near3 mode near3 lock\$3)) and laser near diode	USPAT;	2003/07/27 14:37
	1		US-PGPUB;	
			EPO; JPO;	
		(// / - / / O O O)	DERWENT	0000/07/07 44:00
68	1	(((self near3 mode near3 lock\$3)) and laser near diode) and	USPAT;	2003/07/27 14:38
		perturbation and (misalign\$4 or realign\$4)	US-PGPUB;	
			EPO; JPO;	
		(((((((((((((((((((((DERWENT	0000/07/07 44:00
69	23	(((self near3 mode near3 lock\$3)) and laser near diode) and	USPAT;	2003/07/27 14:38
		(perturbation or misalign\$4 or realign\$4)	US-PGPUB;	
			EPO; JPO;	
			DERWENT	0000107107.40.50
-	2609	semiconductor near laser near diode	USPAT;	2003/07/27 12:53
			US-PGPUB	
-	2084	semiconductor adj laser adj diode	USPAT;	2002/10/19 18:17
			US-PGPUB	
-	95	(semiconductor adj laser adj diode) and mode near lock\$3	USPAT;	2002/10/19 18:18
			US-PGPUB	
-	51	((semiconductor adj laser adj diode) and mode near lock\$3) and	USPAT;	2002/10/19 18:18
		passive\$3	US-PGPUB	
-	20	((semiconductor adj laser adj diode) and mode near lock\$3) and	USPAT;	2002/10/19 18:19
		passive\$3 near mode near lock\$3	US-PGPUB	
-	20	(semiconductor adj laser adj diode) and (passive\$3 near mode	USPAT;	2002/10/19 18:19
	İ	near lock\$3)	US-PGPUB	
-	160	(counterpropagating near (waves or pulses))	USPAT;	2002/10/19 18:41
-	100	(counterpropagating near (waves or pulses))		
-	100		US-PGPUB	
-	100	((counterpropagating near (waves or pulses))) and (passive\$3	US-PGPUB USPAT;	2002/10/19 18:47
-		((counterpropagating near (waves or pulses))) and (passive\$3 near mode near lock\$3)	US-PGPUB	2002/10/19 18:47
		((counterpropagating near (waves or pulses))) and (passive\$3 near mode near lock\$3) (((counterpropagating near (waves or pulses))) and (passive\$3	US-PGPUB USPAT;	2002/10/19 18:47
- -		((counterpropagating near (waves or pulses))) and (passive\$3 near mode near lock\$3)	US-PGPUB USPAT; US-PGPUB	
-		((counterpropagating near (waves or pulses))) and (passive\$3 near mode near lock\$3) (((counterpropagating near (waves or pulses))) and (passive\$3	US-PGPUB USPAT; US-PGPUB USPAT;	
-		((counterpropagating near (waves or pulses))) and (passive\$3 near mode near lock\$3) (((counterpropagating near (waves or pulses))) and (passive\$3 near mode near lock\$3)) and (semiconductor near laser near	US-PGPUB USPAT; US-PGPUB USPAT;	
-	10	((counterpropagating near (waves or pulses))) and (passive\$3 near mode near lock\$3) (((counterpropagating near (waves or pulses))) and (passive\$3 near mode near lock\$3)) and (semiconductor near laser near diode)	US-PGPUB USPAT; US-PGPUB USPAT; US-PGPUB	2002/10/19 18:44
-	10	((counterpropagating near (waves or pulses))) and (passive\$3 near mode near lock\$3) (((counterpropagating near (waves or pulses))) and (passive\$3 near mode near lock\$3)) and (semiconductor near laser near diode) (((counterpropagating near (waves or pulses))) and (passive\$3 near mode near lock\$3)) and (laser near diode)	US-PGPUB USPAT; US-PGPUB USPAT; US-PGPUB USPAT;	2002/10/19 18:44
-	10 1 5	((counterpropagating near (waves or pulses))) and (passive\$3 near mode near lock\$3) (((counterpropagating near (waves or pulses))) and (passive\$3 near mode near lock\$3)) and (semiconductor near laser near diode) (((counterpropagating near (waves or pulses))) and (passive\$3	US-PGPUB USPAT; US-PGPUB USPAT; US-PGPUB USPAT; US-PGPUB	2002/10/19 18:44
-	10 1 5	((counterpropagating near (waves or pulses))) and (passive\$3 near mode near lock\$3) (((counterpropagating near (waves or pulses))) and (passive\$3 near mode near lock\$3)) and (semiconductor near laser near diode) (((counterpropagating near (waves or pulses))) and (passive\$3 near mode near lock\$3)) and (laser near diode)	US-PGPUB USPAT; US-PGPUB USPAT; US-PGPUB USPAT; US-PGPUB USPAT;	2002/10/19 18:44

-	16	(((laser near diode) and (passive\$3 near mode near lock\$3)) not	USPAT;	2002/10/19 18:50
		(saturable adj absorber)) and (align\$4 or misalign\$4)	US-PGPUB	
-	10	misalign\$4 and (passive\$3 near mode near lock\$3)	USPAT;	2002/10/19 18:56
			US-PGPUB	
-	0	misalign\$4 near (passive\$3 near mode near lock\$3)	USPAT;	2002/10/19 19:00
			US-PGPUB	
-	76	self near mode near lock\$3	USPAT;	2002/10/19 19:30
			US-PGPUB	
_	l o	((self near mode near lock\$3) and (laser near diode)) and	USPAT;	2002/10/19 19:02
	"	realign\$4	US-PGPUB	
_	5	((self near mode near lock\$3) and (laser near diode)) and	USPAT;	2002/10/19 19:02
_		misalign\$4	US-PGPUB	2002/10/10 10:02
	25	(self near mode near lock\$3) and (laser near diode)	USPAT:	2002/10/19 19:06
-	25	(sell fleat floue fleat lock\$5) and (laser fleat diode)	US-PGPUB	2002/10/13 13.00
	40	(/ask assumed assumes (sol(02)) and (laser assumed diada)) ast	USPAT;	2002/40/40 40/20
-	18	((self near mode near lock\$3) and (laser near diode)) not		2002/10/19 19:30
	_	(saturable adj absorber)	US-PGPUB	2000/40/40 40-24
-	5	(self near mode near lock\$3) and ring near cavity	USPAT;	2002/10/19 19:31
			US-PGPUB	0000404040
-	185	(laser near diode) and (ring near cavity)	USPAT;	2002/10/19 19:32
			US-PGPUB	
-	62	((laser near diode) and (ring near cavity)) and (mode near lock\$3)	USPAT;	2002/10/19 19:39
			US-PGPUB	
-	j 37	(((laser near diode) and (ring near cavity)) and (mode near	USPAT;	2002/10/19 19:33
		lock\$3)) and (self or passive\$3)	US-PGPUB	
-	22	((((laser near diode) and (ring near cavity)) and (mode near	USPAT;	2002/10/19 19:33
		lock\$3)) and (self or passive\$3)) not (saturable adj absorber)	US-PGPUB	
-	1	((laser near diode) and (ring near cavity)) and (self near mode	USPAT;	2002/10/19 19:45
		near lock\$3)	US-PGPUB	
-	2084	semiconductor adj laser adj diode	USPAT;	2002/10/19 19:46
			US-PGPUB	
_	18	(semiconductor adj laser adj diode) and 372/94.ccls.	USPAT:	2002/10/19 19:51
		(US-PGPUB	
-	1 1	((semiconductor adj laser adj diode) and 372/94.ccls.) and	USPAT:	2002/10/19 19:48
	'	(passive\$3 near mode near lock\$3)	US-PGPUB	
_	0	((semiconductor adj laser adj diode) and 372/94.ccls.) and (self	USPAT:	2002/10/19 19:48
		near mode near lock\$3)	US-PGPUB	
_	6	((semiconductor adj laser adj diode) and 372/94.ccls.) and (mode	USPAT;	2002/10/19 19:48
-	0	near lock\$3)	US-PGPUB	2302/10/10 10:40
	99	laser adj diode and 372/94.ccls.	USPAT;	2002/10/19 19:52
-	99	laser auj ulture ariu 372/34.0018.	US-PGPUB	2002/10/19 19:02
		/loops adjidiada and 272/04 pole \ and salf adj made adjilastina		2002/10/19 19:52
-	1	(laser adj diode and 372/94.ccls.) and self adj mode adj locking	USPAT;	2002/10/19 19:52
		((US-PGPUB	2002/40/40 40/55
-	6	(laser adj diode and 372/94.ccls.) and passive adj mode adj	USPAT;	2002/10/19 19:55
		locking	US-PGPUB	0000/40/40 40:50
-	50	(semiconductor adj laser adj diode) and ((ring near cavity) or (ring	USPAT;	2002/10/19 19:56
	1	near laser))	US-PGPUB	00004040405
-	1	((semiconductor adj laser adj diode) and ((ring near cavity) or	USPAT;	2002/10/19 19:57
		(ring near laser))) and ((self adj mode adj lock\$3) or (passive adj	US-PGPUB	
		mode adj lock\$3))	L	